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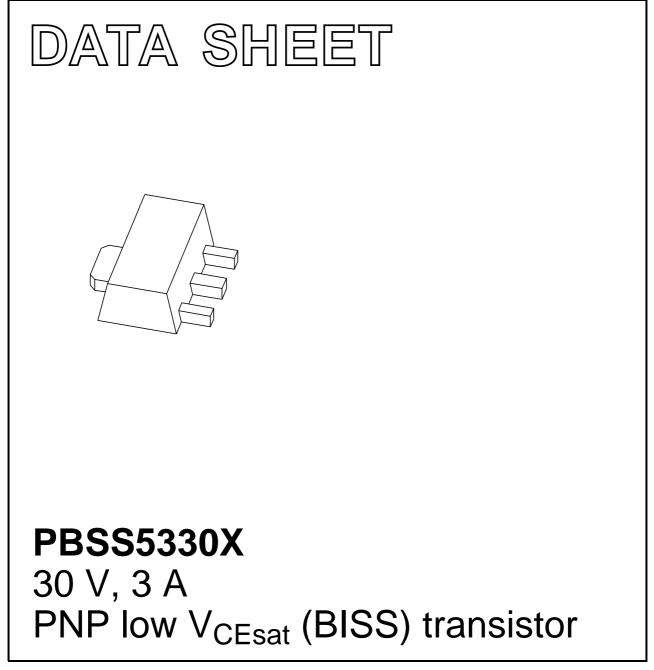
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Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 2003 Nov 28 2004 Nov 03



30 V, 3 A PNP low V_{CEsat} (BISS) transistor

FEATURES

- SOT89 (SC-62) package
- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability: I_C and I_{CM}
- Higher efficiency leading to less heat generation
- Reduced printed-circuit board requirements.

APPLICATIONS

- Power management
 - DC/DC converters
 - Supply line switching
 - Battery charger
 - LCD backlighting.
- Peripheral drivers
 - Driver in low supply voltage applications (e.g. lamps and LEDs)
 - Inductive load driver (e.g. relays, buzzers and motors).

DESCRIPTION

PNP low V_{CEsat} transistor in a SOT89 plastic package.

MARKING

| TYPE NUMBER | MARKING CODE ⁽¹⁾ |
|-------------|-----------------------------|
| PBSS5330X | *1S |

Note

- 1. * = p: Made in Hong Kong.
 - * = t: Made in Malaysia.
 - * = W: Made in China.

ORDERING INFORMATION

| TYPE NUMBER | PACKAGE | | | |
|------------------|---------|--|---------|--|
| NAME DESCRIPTION | | DESCRIPTION | VERSION | |
| PBSS5330X | SC-62 | SC-62 plastic surface mounted package; collector pad for good heat transfer; 3 leads | | |

QUICK REFERENCE DATA

| SYMBOL | PARAMETER | MAX. | UNIT |
|--------------------|------------------------------|------|------|
| V _{CEO} | collector-emitter voltage | -30 | V |
| I _C | collector current (DC) -3 | | А |
| I _{CM} | peak collector current -5 | | А |
| R _{CEsat} | equivalent on-resistance 107 | | mΩ |

PINNING

| PIN | DESCRIPTION | |
|-----|-------------|--|
| 1 | emitter | |
| 2 | collector | |
| 3 | base | |

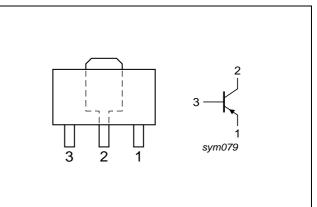


Fig.1 Simplified outline (SOT89) and symbol.

2004 Nov 03

PBSS5330X

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|---------------------------|--------------------------------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | - | -30 | V |
| V _{CEO} | collector-emitter voltage | open base | — | -30 | V |
| V _{EBO} | emitter-base voltage | open collector | — | -6 | V |
| I _C | collector current (DC) | note 4 | - | -3 | A |
| I _{CM} | peak collector current | limited by T _{j(max)} | - | -5 | А |
| I _B | base current (DC) | | — | -0.5 | A |
| P _{tot} | total power dissipation | $T_{amb} \le 25 \ ^{\circ}C$ | | | |
| | | note 1 | _ | 550 | mW |
| | | note 2 | _ | 1 | W |
| | | note 3 | _ | 1.4 | W |
| | | note 4 | _ | 1.6 | W |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -65 | +150 | °C |

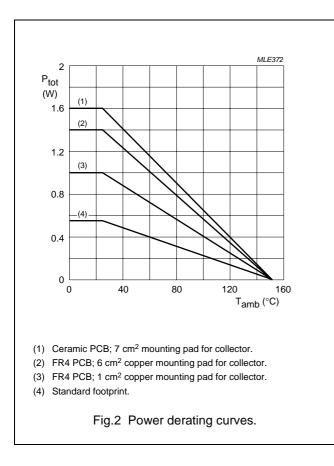
Notes

1. Device mounted on a FR4 printed-circuit board; single-sided copper; tin-plated; standard footprint.

2. Device mounted on a FR4 printed-circuit board; single-sided copper; tin-plated; mounting pad for collector 1 cm².

3. Device mounted on a FR4 printed-circuit board; single-sided copper; tin-plated; mounting pad for collector 6 cm².

4. Device mounted on a ceramic printed-circuit board 7 cm², single-sided copper, tin-plated.



PBSS5330X

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------------|---|-------------|-------|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | | |
| | | note 1 | 225 | K/W |
| | | note 2 | 125 | K/W |
| | | note 3 | 90 | K/W |
| | | note 4 | 80 | K/W |
| R _{th(j-s)} | thermal resistance from junction to soldering point | | 16 | K/W |

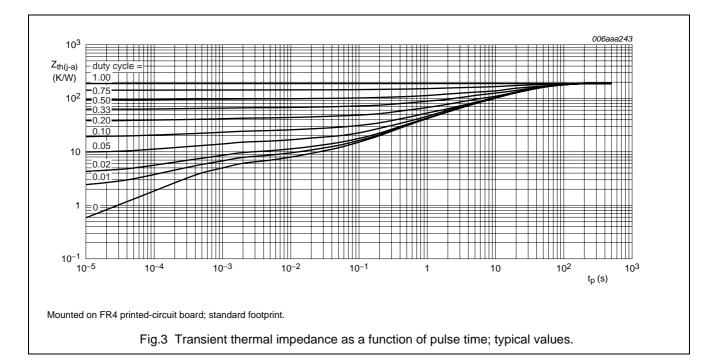
Notes

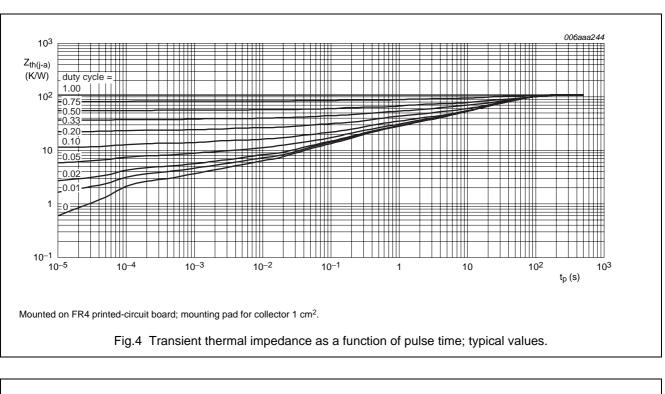
1. Device mounted on a FR4 printed-circuit board; single-sided copper; tin-plated; standard footprint.

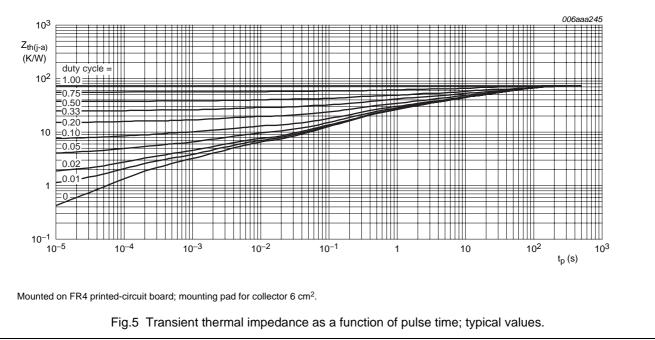
2. Device mounted on a FR4 printed-circuit board; single-sided copper; tin-plated; mounting pad for collector 1 cm².

3. Device mounted on a FR4 printed-circuit board; single-sided copper; tin-plated; mounting pad for collector 6 cm².

4. Device mounted on a ceramic printed-circuit board 7 cm², single-sided copper, tin-plated.







30 V, 3 A PNP low V_{CEsat} (BISS) transistor

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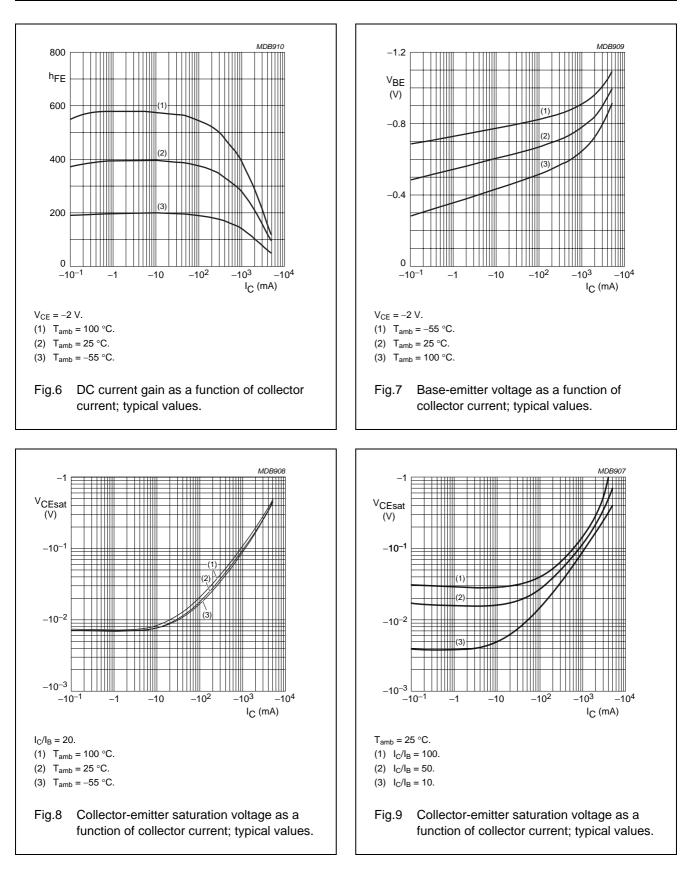
CHARACTERISTICS

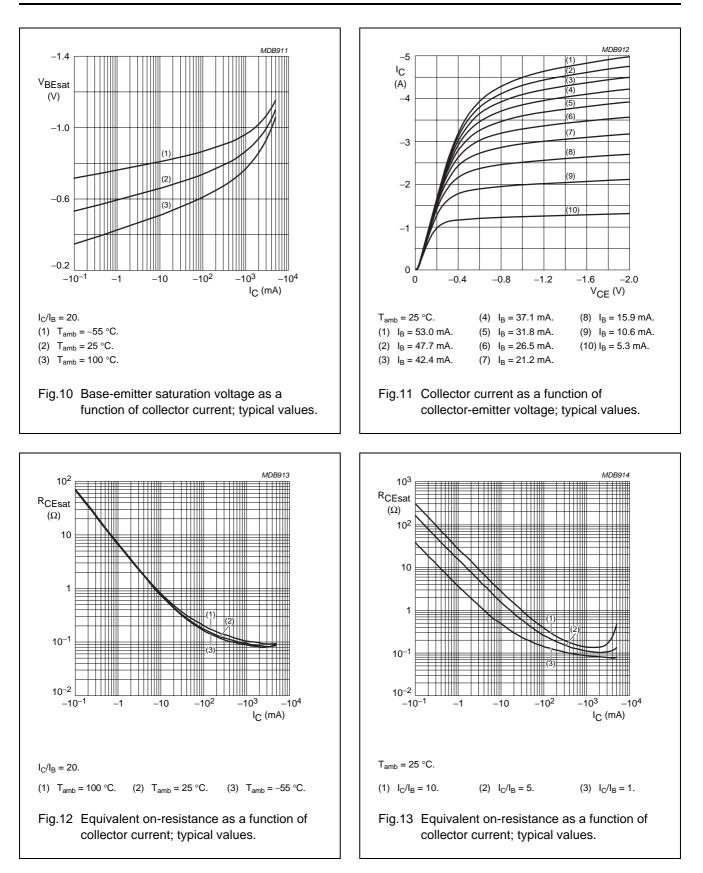
 T_{amb} = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--------------------|-----------------------------------|---|------|------|------|------|
| I _{CBO} | collector-base cut-off current | $V_{CB} = -30 \text{ V}; \text{ I}_{E} = 0 \text{ A}$ | _ | _ | -100 | nA |
| | | $V_{CB} = -30 \text{ V}; \text{ I}_{E} = 0 \text{ A}; \text{ T}_{j} = 150 ^{\circ}\text{C}$ | - | - | -50 | μA |
| I _{CES} | collector-emitter cut-off current | $V_{CE} = -30 \text{ V}; \text{ V}_{BE} = 0 \text{ V}$ | - | - | -100 | nA |
| I _{EBO} | emitter-base cut-off current | $V_{EB} = -5 V; I_C = 0 A$ | - | - | -100 | nA |
| h _{FE} | DC current gain | $V_{CE} = -2 V$ | | | | |
| | | $I_{\rm C} = -0.1 {\rm A}$ | 200 | - | - | |
| | | I _C = -0.5 A | 200 | - | - | |
| | | I _C = −1 A; note 1 | 175 | - | 450 | |
| | | I _C = -2 A; note 1 | 140 | - | - | |
| | | I _C = -3 A; note 1 | 100 | - | - | |
| V _{CEsat} | collector-emitter saturation | $I_{\rm C} = -0.5 \text{ A}; I_{\rm B} = -50 \text{ mA}$ | - | - | -70 | mV |
| | voltage | $I_{\rm C} = -1$ A; $I_{\rm B} = -50$ mA | - | - | -130 | mV |
| | | $I_{\rm C} = -2$ A; $I_{\rm B} = -100$ mA | - | - | -240 | mV |
| | | $I_{C} = -3 \text{ A}; I_{B} = -300 \text{ mA}; \text{ note } 1$ | - | - | -320 | mV |
| R _{CEsat} | equivalent on-resistance | $I_{\rm C} = -3$ A; $I_{\rm B} = -300$ mA; note 1 | - | 80 | 107 | mΩ |
| V _{BEsat} | base-emitter saturation voltage | $I_{\rm C} = -2$ A; $I_{\rm B} = -100$ mA | _ | _ | -1.1 | V |
| | | $I_{C} = -3 \text{ A}; I_{B} = -300 \text{ mA}; \text{ note } 1$ | _ | _ | -1.2 | V |
| V _{BEon} | base-emitter turn-on voltage | $V_{CE} = -2 \text{ V}; \text{ I}_{C} = -1 \text{ A}$ | -1.0 | - | - | V |
| f _T | transition frequency | $I_{C} = -100 \text{ mA}; V_{CE} = -5 \text{ V};$ f = 100 MHz | 100 | - | - | MHz |
| C _c | collector capacitance | $V_{CB} = -10 \text{ V}; \text{ I}_{E} = \text{i}_{e} = 0 \text{ A}; \text{ f} = 1 \text{ MHz}$ | - | - | 45 | pF |

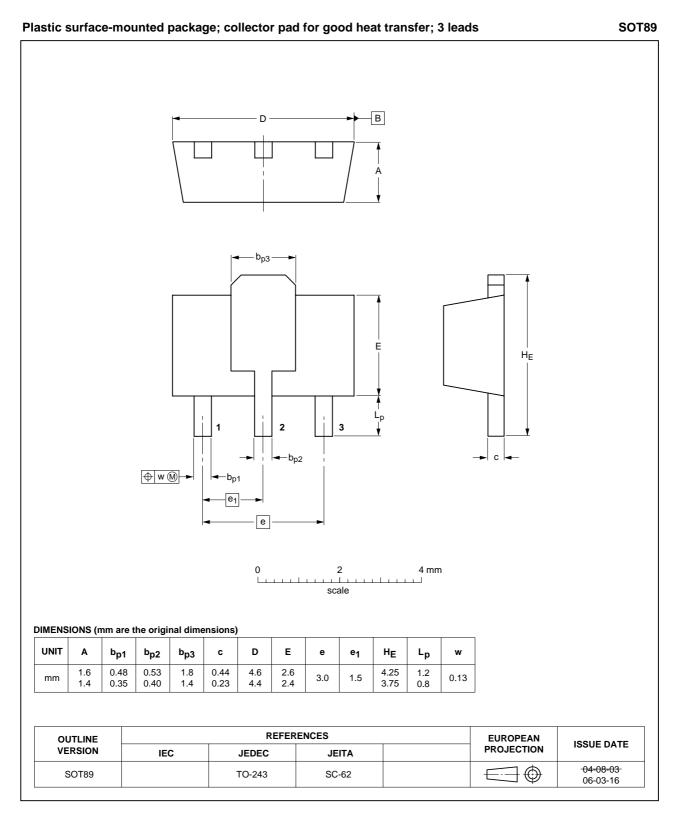
Note

1. Pulse test: $t_p \leq 300~\mu s;~\delta \leq 0.02.$





PACKAGE OUTLINE



PBSS5330X

DATA SHEET STATUS

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|-----------------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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NXP Semiconductors

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This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

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